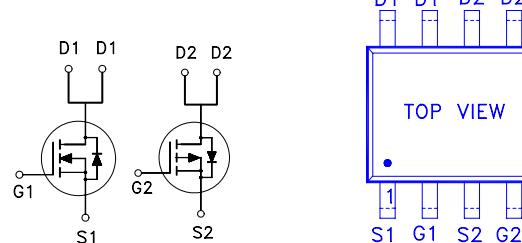


NIKO-SEM**N- & P-Channel Enhancement Mode
Field Effect Transistor****P3503QVG**
SOP-8
Lead-Free**PRODUCT SUMMARY**

| | $V_{(BR)DSS}$ | $R_{DS(ON)}$ | I_D |
|-----------|---------------|--------------|-------|
| N-Channel | 30 | 25m | 7A |
| P-Channel | -30 | 35m | -6A |



G : GATE
D : DRAIN
S : SOURCE

ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$ Unless Otherwise Noted)

| PARAMETERS/TEST CONDITIONS | SYMBOL | N-Channel | P-Channel | UNITS |
|--------------------------------------|----------------|------------|-----------|-------|
| Drain-Source Voltage | V_{DS} | 30 | -30 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | ± 20 | V |
| Continuous Drain Current | I_D | 7 | -6 | A |
| | | 6 | -5 | |
| Pulsed Drain Current ¹ | I_{DM} | 20 | -20 | |
| Power Dissipation | P_D | 2 | 1.3 | W |
| | | 1.3 | | |
| Junction & Storage Temperature Range | T_j, T_{stg} | -55 to 150 | | °C |

THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | SYMBOL | TYPICAL | MAXIMUM | UNITS |
|---------------------|-----------------|---------|---------|--------|
| Junction-to-Ambient | $R_{\theta JA}$ | 48 | 62.5 | °C / W |

¹Pulse width limited by maximum junction temperature.²Duty cycle $\leq 1\%$ **ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$, Unless Otherwise Noted)**

| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNIT |
|--------------------------------|---------------|------------------------------------------|--------|-----|------|-----------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu\text{A}$ | N-Ch | 30 | | V |
| | | $V_{GS} = 0V, I_D = -250\mu\text{A}$ | P-Ch | -30 | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | N-Ch | 1 | 1.5 | 2.5 |
| | | $V_{DS} = V_{GS}, I_D = -250\mu\text{A}$ | P-Ch | -1 | -1.5 | -2.5 |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 20V$ | N-Ch | | | ± 100 |
| | | $V_{DS} = 0V, V_{GS} = \pm 20V$ | P-Ch | | | nA |

NIKO-SEM
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| | | | | | | | |
|---------------------------------------|-------------|------------------------------------------------|------|------|----|-----|---------|
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 24V, V_{GS} = 0V$ | N-Ch | | | 1 | μA |
| | | $V_{DS} = -24V, V_{GS} = 0V$ | P-Ch | | | -1 | |
| | | $V_{DS} = 20V, V_{GS} = 0V, T_J = 55^\circ C$ | N-Ch | | | 10 | μA |
| | | $V_{DS} = -20V, V_{GS} = 0V, T_J = 55^\circ C$ | | P-Ch | | -10 | |
| On-State Drain Current ¹ | $I_{D(ON)}$ | $V_{DS} = 5V, V_{GS} = 10V$ | N-Ch | 20 | | | A |
| | | $V_{DS} = -5V, V_{GS} = -10V$ | P-Ch | -20 | | | |
| Drain-Source Resistance ¹ | On-State | $V_{GS} = 4.5V, I_D = 6A$ | N-Ch | | 25 | 37 | m |
| | | $V_{GS} = -4.5V, I_D = -5A$ | P-Ch | | 44 | 60 | |
| | | $V_{GS} = 10V, I_D = 7A$ | N-Ch | | 18 | 25 | |
| | | $V_{GS} = -10V, I_D = -6A$ | P-Ch | | 28 | 35 | |
| Forward Transconductance ¹ | g_{fs} | $V_{DS} = 5V, I_D = 7A$ | N-Ch | | 19 | | S |
| | | $V_{DS} = -5V, I_D = -5A$ | P-Ch | | 10 | | |

DYNAMIC

| | | | | | | |
|----------------------------------|--------------|-------------------------------------------------------------------------|------|-----|------|----|
| Input Capacitance | C_{iss} | N-Channel $V_{GS} = 0V, V_{DS} = 10V, f = 1MHz$ | N-Ch | 790 | 988 | pF |
| Output Capacitance | C_{oss} | | P-Ch | 970 | 1213 | |
| Reverse Transfer Capacitance | C_{rss} | | N-Ch | 175 | 245 | pF |
| | | | P-Ch | 370 | 520 | |
| Total Gate Charge ² | Q_g | N-Channel $V_{DS} = 0.5V_{(BR)DSS}, V_{GS} = 10V,$ $I_D = 6A$ | N-Ch | 65 | 98 | nC |
| Gate-Source Charge ² | Q_{gs} | | P-Ch | 180 | 270 | |
| Gate-Drain Charge ² | Q_{gd} | | N-Ch | 16 | | nC |
| | | | P-Ch | 28 | | |
| Turn-On Delay Time ² | $t_{d(on)}$ | N-Channel $V_{DD} = 10V$ $I_D \geq 1A, V_{GS} = 10V, R_{GEN} = 6$ | N-Ch | 2.5 | | ns |
| Rise Time ² | t_r | | P-Ch | 6 | | |
| Turn-Off Delay Time ² | $t_{d(off)}$ | | N-Ch | 2.1 | | |
| Fall Time ² | t_f | | P-Ch | 12 | | |

NIKO-SEM**N- & P-Channel Enhancement Mode
Field Effect Transistor****P3503QVG**
SOP-8
Lead-Free

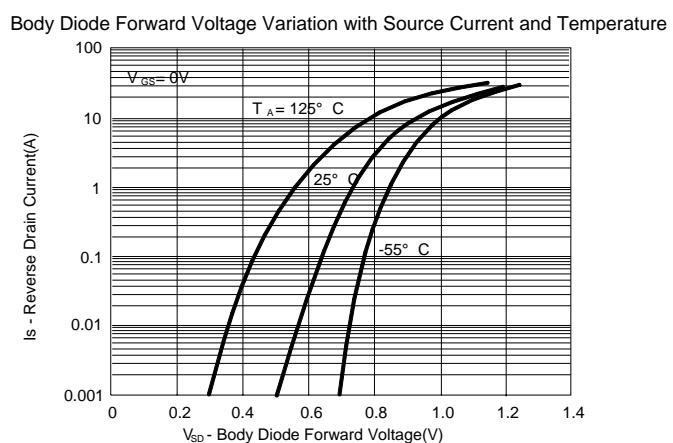
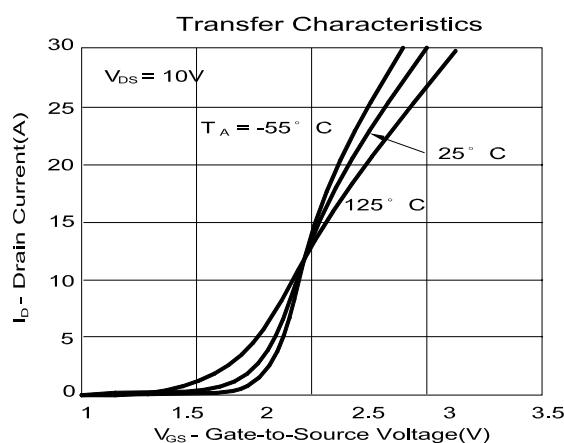
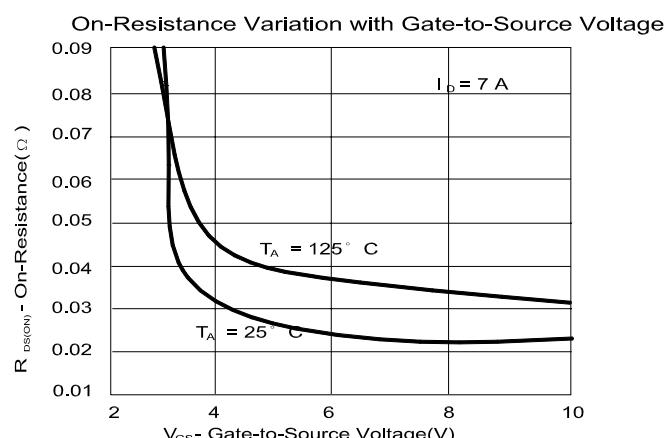
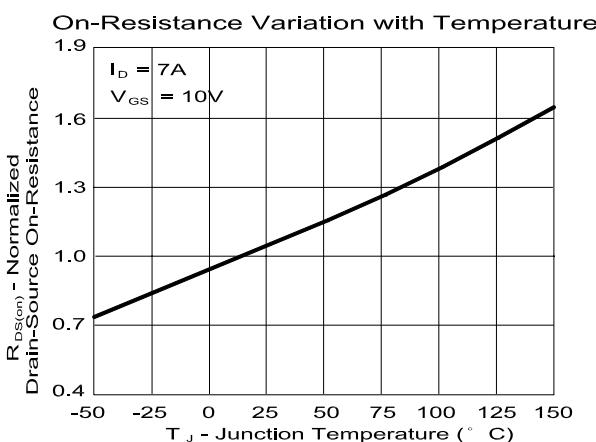
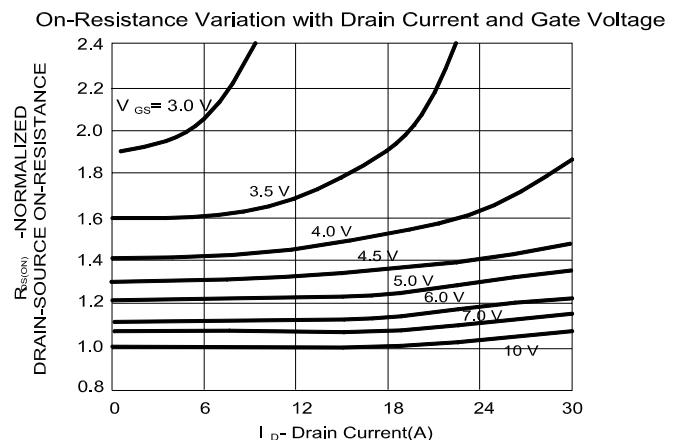
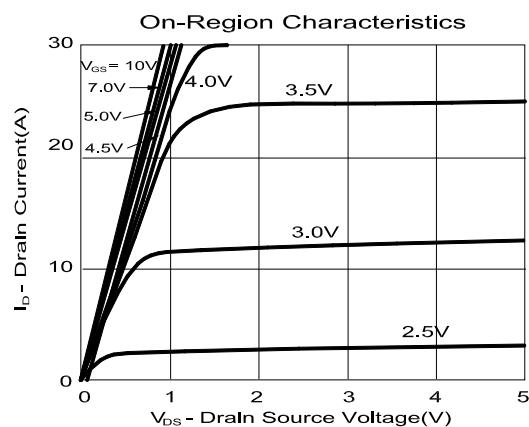
| SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_C = 25^\circ\text{C}$) | | | | | | | |
|-----------------------------------------------------------------------------|----------|----------------------------------------|------|--|--|------|---|
| Continuous Current | I_S | | N-Ch | | | 1.3 | A |
| | | | P-Ch | | | -1.3 | |
| Pulsed Current ³ | I_{SM} | | N-Ch | | | 2.6 | A |
| | | | P-Ch | | | -2.6 | |
| Forward Voltage ¹ | V_{SD} | $I_F = 1\text{A}, V_{GS} = 0\text{V}$ | N-Ch | | | 1 | V |
| | | $I_F = -1\text{A}, V_{GS} = 0\text{V}$ | P-Ch | | | -1 | |

¹Pulse test : Pulse Width $\leq 300 \mu\text{sec}$, Duty Cycle $\leq 2\%$.²Independent of operating temperature.³Pulse width limited by maximum junction temperature.**REMARK: THE PRODUCT MARKED WITH “P3503QVG”, DATE CODE or LOT #**

Orders for parts with Lead-Free plating can be placed using the PXXXXXXG parts name.

TYPICAL PERFORMANCE CHARACTERISTICS

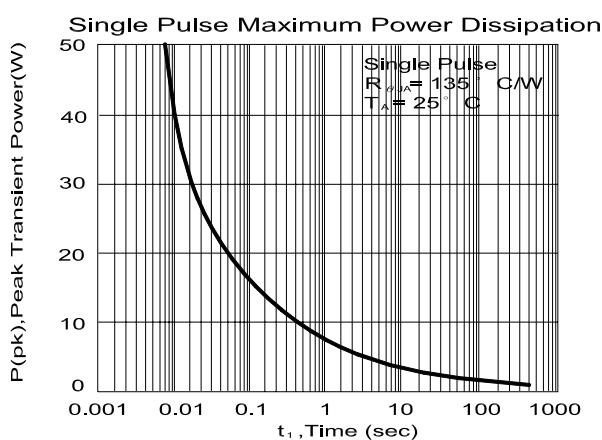
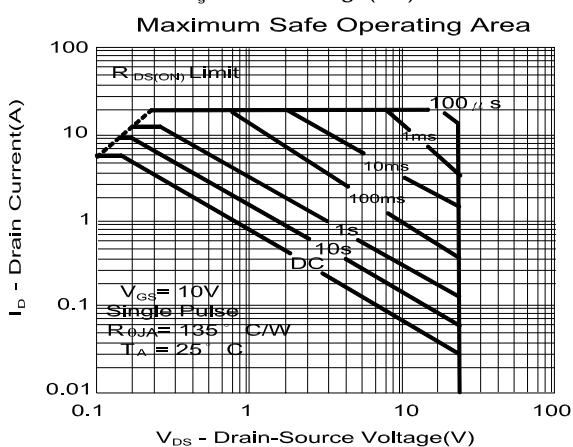
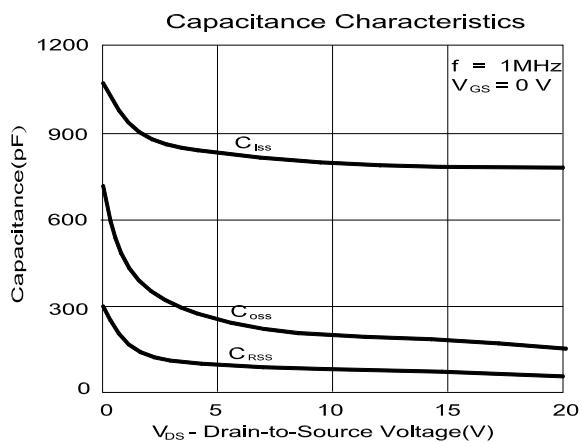
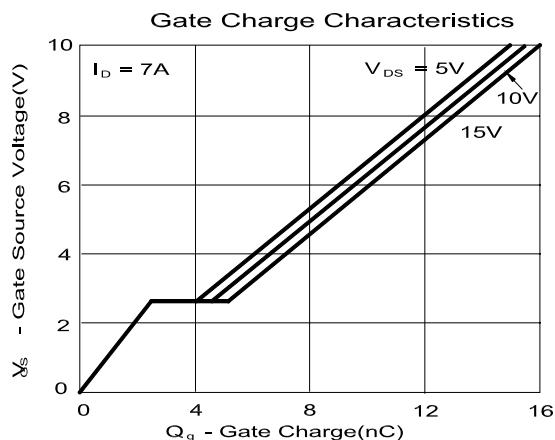
N-CHANNEL

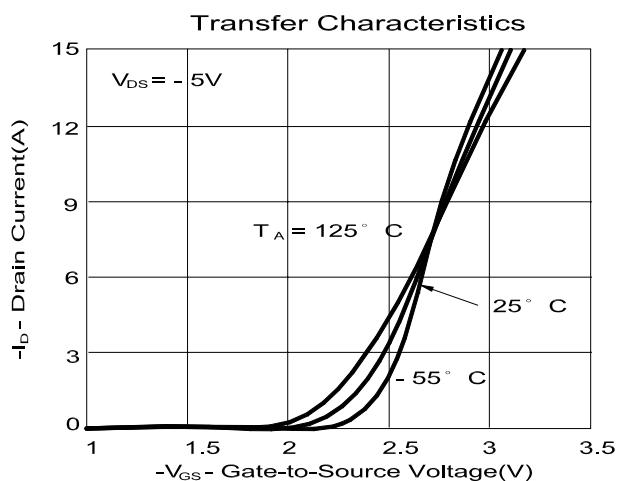
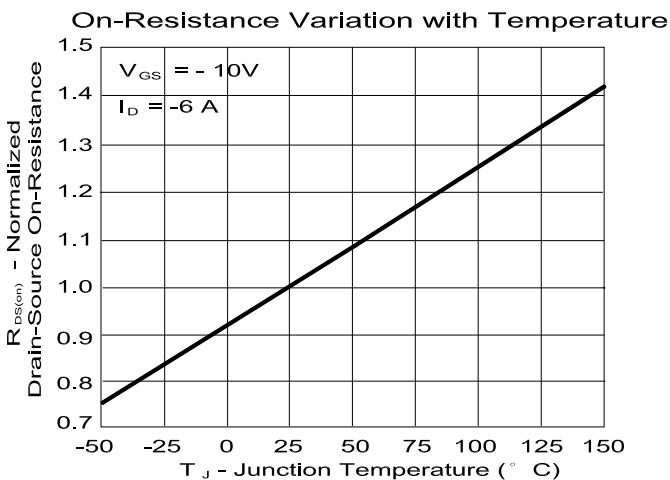
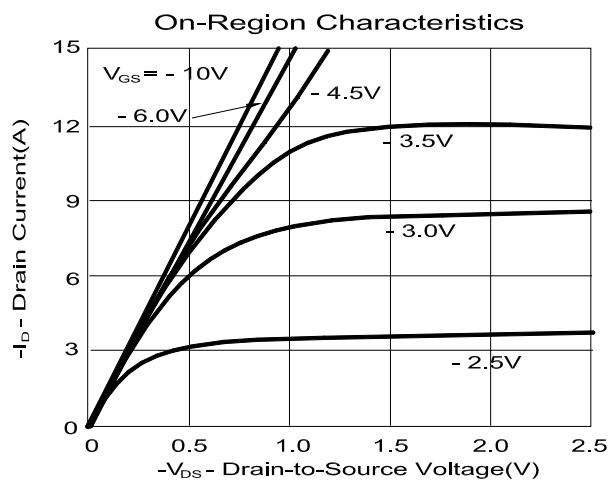
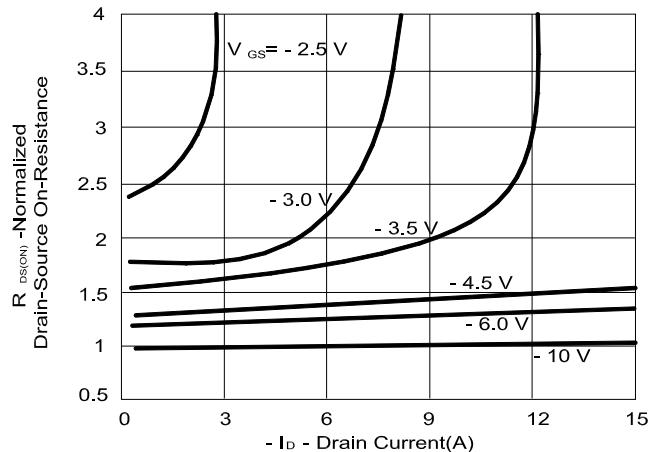
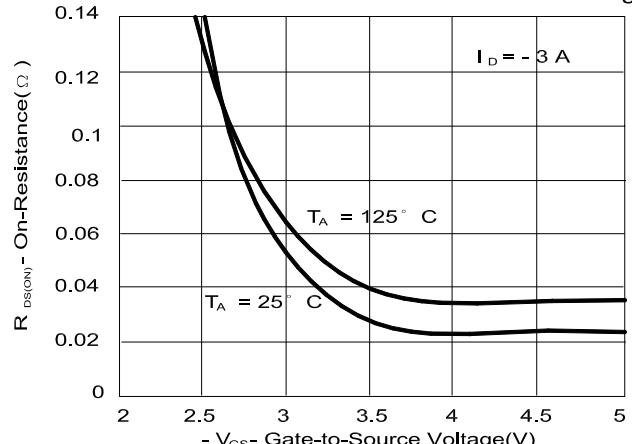
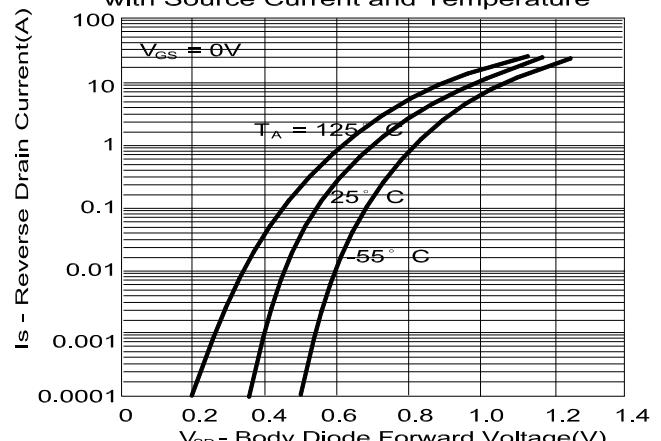


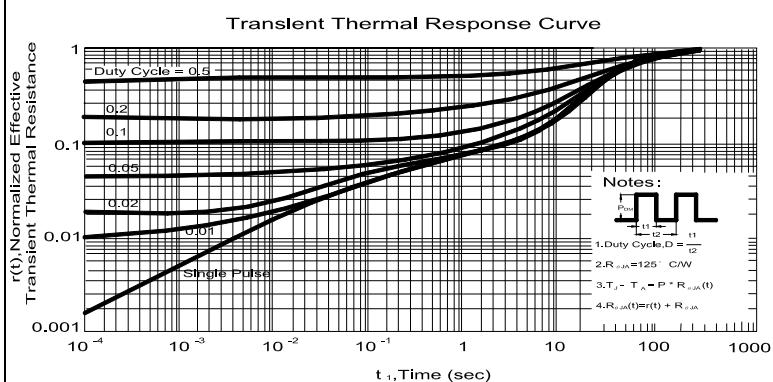
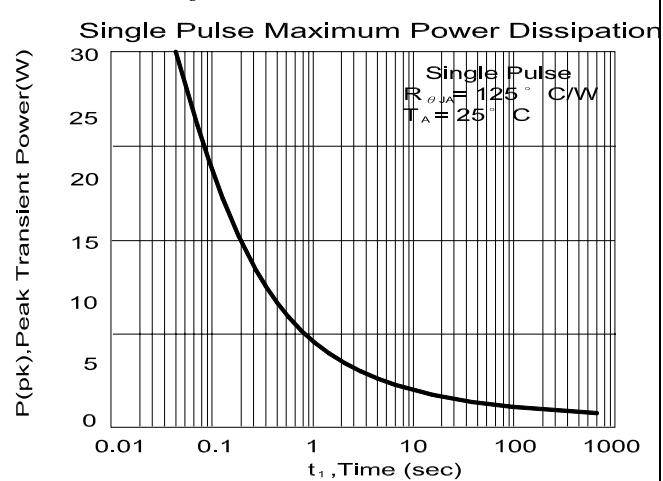
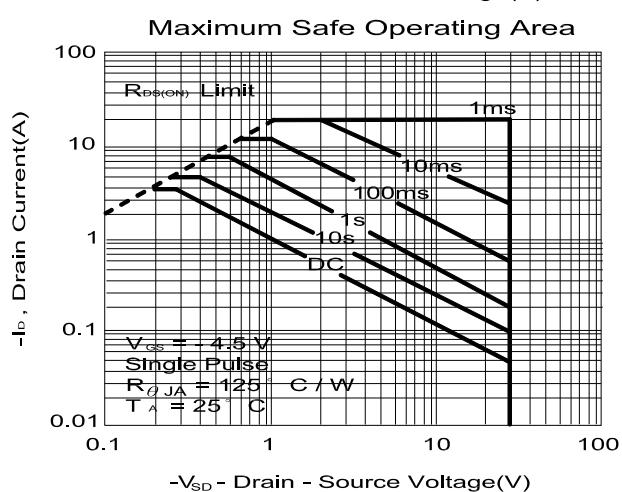
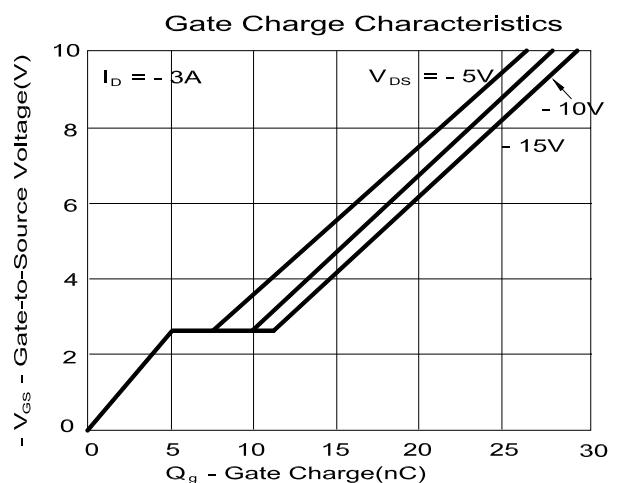
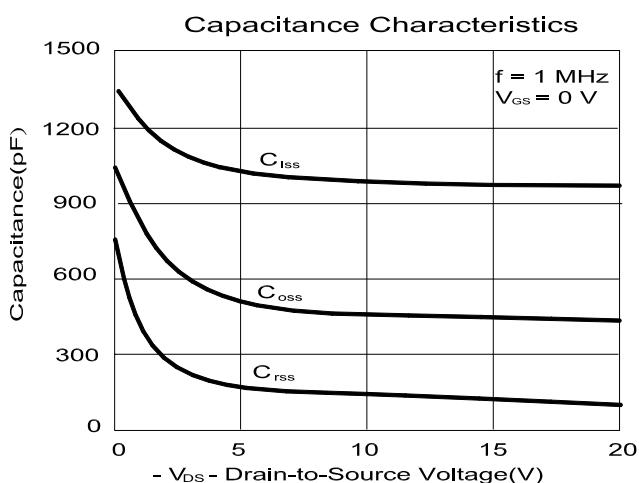
NIKO-SEM

**N- & P-Channel Enhancement Mode
Field Effect Transistor**

P3503QVG
SOP-8
Lead-Free



P-CHANNEL**On-Resistance Variation with Drain Current and Gate Voltage****On-Resistance Variation with Gate-to-Source Voltage****Body Diode Forward Voltage Variation with Source Current and Temperature**

NIKO-SEM**N- & P-Channel Enhancement Mode
Field Effect Transistor****P3503QVG
SOP-8
Lead-Free**

SOIC-8(D) MECHANICAL DATA

| Dimension | mm | | | Dimension | mm | | |
|-----------|------|-------|------|-----------|------|-------|------|
| | Min. | Typ. | Max. | | Min. | Typ. | Max. |
| A | 4.8 | 4.9 | 5.0 | H | 0.5 | 0.715 | 0.83 |
| B | 3.8 | 3.9 | 4.0 | I | 0.18 | 0.254 | 0.25 |
| C | 5.8 | 6.0 | 6.2 | J | | 0.22 | |
| D | 0.38 | 0.445 | 0.51 | K | 0° | 4° | 8° |
| E | | 1.27 | | L | | | |
| F | 1.35 | 1.55 | 1.75 | M | | | |
| G | 0.1 | 0.175 | 0.25 | N | | | |

